onsemi

Automotive Inductive Load Driver

NUD3124, SZNUD3124

This micro-integrated part provides a single component solution to switch inductive loads such as relays, solenoids, and small DC motors without the need of a free-wheeling diode. It accepts logic level inputs, thus allowing it to be driven by a large variety of devices including logic gates, inverters, and microcontrollers.

Features

- Provides Robust Interface between D.C. Relay Coils and Sensitive Logic
- Capable of Driving Relay Coils Rated up to 150 mA at 12 Volts
- Replaces 3 or 4 Discrete Components for Lower Cost
- Internal Zener Eliminates Need for Free–Wheeling Diode
- Meets Load Dump and other Automotive Specs
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Automotive and Industrial Environment
- Drives Window, Latch, Door, and Antenna Relays

Benefits

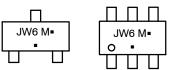
- Reduced PCB Space
- Standardized Driver for Wide Range of Relays
- Simplifies Circuit Design and PCB Layout
- Compliance with Automotive Specifications



SOT-23 CASE 318 STYLE 21

SC-74 CASE 318F STYLE 7

MARKING DIAGRAMS



JW6 = Specific Device Code

= Date Code

Μ

= Pb-Free Package

(Note: Microdot may be in either location)

JW6 = Specific Device Code

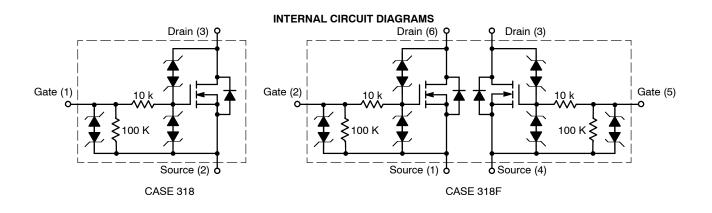
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NUD3124LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SZNUD3124LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NUD3124DMT1G	SC–74 (Pb–Free)	3000 / Tape & Reel
SZNUD3124DMT1G	SC–74 (Pb–Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.



Symbol	Rating	Value	Unit
V _{DSS}	Drain-to-Source Voltage – Continuous $(T_J = 125^{\circ}C)$	28	V
V _{GSS}	Gate-to-Source Voltage – Continuous $(T_J = 125^{\circ}C)$	12	V
Ι _D	Drain Current – Continuous $(T_J = 125^{\circ}C)$	150	mA
Ez	Single Pulse Drain-to-Source Avalanche Energy (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	250	mJ
P _{PK}	Peak Power Dissipation, Drain-to-Source (Notes 1 and 2) (T _J Initial = 85°C)	20	W
E _{LD1}	Load Dump Suppressed Pulse, Drain-to-Source (Notes 3 and 4) (Suppressed Waveform: $V_s = 45 V$, $R_{SOURCE} = 0.5 \Omega$, T = 200 ms) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	80	V
E _{LD2}	Inductive Switching Transient 1, Drain-to-Source (Waveform: $R_{SOURCE} = 10 \Omega$, T = 2.0 ms) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	100	V
E _{LD3}	Inductive Switching Transient 2, Drain-to-Source (Waveform: $R_{SOURCE} = 4.0 \Omega$, T = 50 µs) (For Relay's Coils/Inductive Loads of 80 Ω or Higher) (T _J Initial = 85°C)	300	V
Rev-Bat	Reverse Battery, 10 Minutes (Drain-to-Source) (For Relay's Coils/Inductive Loads of 80 Ω or more)	-14	V
Dual-Volt	Dual Voltage Jump Start, 10 Minutes (Drain-to-Source)	28	V
ESD	Human Body Model (HBM) According to EIA/JESD22/A114 Specification	2,000	V

MAXIMUM RATINGS (T_J = 25° C unless otherwise specified)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality Stresses exceeding those listed in the Maximum Hatings table may demay of should not be assumed, damage may occur and reliability may be affected.
Nonrepetitive current square pulse 1.0 ms duration.
For different square pulse durations, see Figure 2.
Nonrepetitive load dump suppressed pulse per Figure 3.
For relay's coils/inductive loads higher than 80 Ω, see Figure 4.

THERMAL CHARACTERISTICS

Symbol	Symbol Rating		Value	Unit
T _A	Operating Ambient Temperature		-40 to 125	°C
TJ	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-65 to 150	°C
PD	Total Power Dissipation (Note 5) Derating above 25°C	SOT-23	225 1.8	mW mW/°C
PD	Total Power Dissipation (Note 5) Derating above 25°C	SC-74	380 3.0	mW mW/°C
$R_{ hetaJA}$	Thermal Resistance Junction-to-Ambient (Note 5)	SOT-23 SC-74	556 329	°C/W

5. Mounted onto minimum pad board.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Drain to Source Sustaining Voltage (I _D = 10 mA)	V _{BRDSS}	28	34	38	V
$ Drain to Source Leakage Current \\ (V_{DS} = 12 V, V_{GS} = 0 V) \\ (V_{DS} = 12 V, V_{GS} = 0 V, T_J = 125^{\circ}C) \\ (V_{DS} = 28 V, V_{GS} = 0 V) \\ (V_{DS} = 28 V, V_{GS} = 0 V, T_J = 125^{\circ}C) \\ \end{array} $	IDSS	- - - -	- - - -	0.5 1.0 50 80	μΑ
Gate Body Leakage Current $(V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V})$ $(V_{GS} = 3.0 \text{ V}, V_{DS} = 0 \text{ V}, T_J = 125^{\circ}\text{C})$ $(V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V})$ $(V_{GS} = 5.0 \text{ V}, V_{DS} = 0 \text{ V}, T_J = 125^{\circ}\text{C})$	l _{GSS}	- - -	- - -	60 80 90 110	μΑ
ON CHARACTERISTICS					
Gate Threshold Voltage $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA})$ $(V_{GS} = V_{DS}, I_D = 1.0 \text{ mA}, T_J = 125^{\circ}\text{C})$	V _{GS(th)}	1.3 1.3	1.8 -	2.0 2.0	V
$ Drain to Source On-Resistance \\ (I_D = 150 mA, V_{GS} = 3.0 V) \\ (I_D = 150 mA, V_{GS} = 3.0 V, T_J = 125^{\circ}C) \\ (I_D = 150 mA, V_{GS} = 5.0 V) \\ (I_D = 150 mA, V_{GS} = 5.0 V, T_J = 125^{\circ}C) $	R _{DS(on)}	- - -	- - -	1.4 1.7 0.8 1.1	Ω
Output Continuous Current ($V_{DS} = 0.25 V$, $V_{GS} = 3.0 V$) ($V_{DS} = 0.25 V$, $V_{GS} = 3.0 V$, $T_J = 125^{\circ}C$)	I _{DS(on)}	150 140	200 -		mA
Forward Transconductance $(V_{DS} = 12 \text{ V}, I_D = 150 \text{ mA})$	9fs	-	500	-	mmho
DYNAMIC CHARACTERISTICS	-	-	-	-	-
Input Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	Ciss	-	32	_	pf
Output Capacitance $(V_{DS} = 12 \text{ V}, V_{GS} = 0 \text{ V}, f = 10 \text{ kHz})$	Coss	-	21	_	pf
Transfer Capacitance (V _{DS} = 12 V, V _{GS} = 0 V, f = 10 kHz)	Crss	-	8.0	-	pf
SWITCHING CHARACTERISTICS					
Propagation Delay Times: High to Low Propagation Delay; Figure 1, $(V_{DS} = 12 \text{ V}, V_{GS} = 3.0 \text{ V})$ Low to High Propagation Delay; Figure 1, $(V_{DS} = 12 \text{ V}, V_{GS} = 3.0 \text{ V})$	t _{PHL} t _{PLH}		890 912		ns
High to Low Propagation Delay; Figure 1, (V_{DS} = 12 V, V_{GS} = 5.0 V) Low to High Propagation Delay; Figure 1, (V_{DS} = 12 V, V_{GS} = 5.0 V)	t _{PHL} t _{PLH}	_	324 1280	-	
Transition Times: Fall Time; Figure 1, (V_{DS} = 12 V, V_{GS} = 3.0 V) Rise Time; Figure 1, (V_{DS} = 12 V, V_{GS} = 3.0 V)	t _f t _r		2086 708		ns
Fall Time; Figure 1, (V $_{DS}$ = 12 V, V $_{GS}$ = 5.0 V) Rise Time; Figure 1, (V $_{DS}$ = 12 V, V $_{GS}$ = 5.0 V)	t _f t _r		556 725	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CURVES

 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$

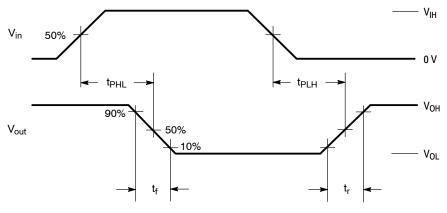
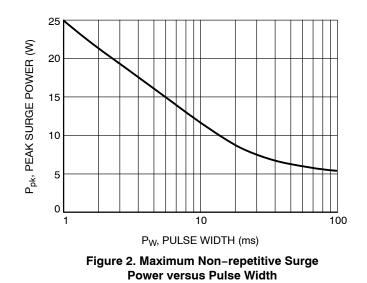


Figure 1. Switching Waveforms



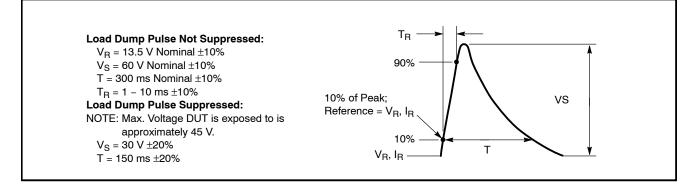
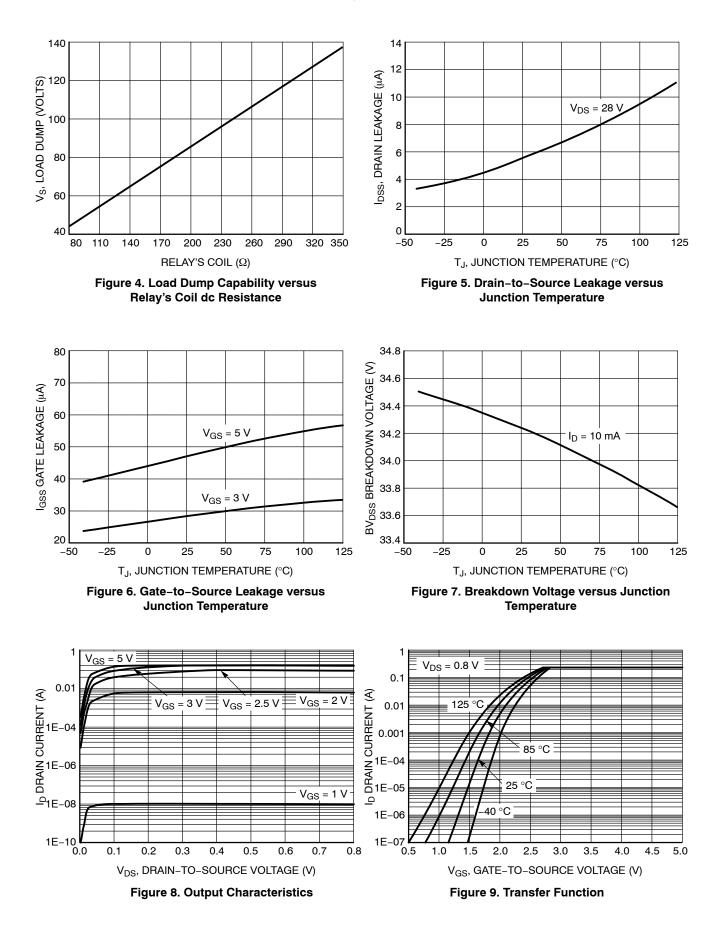


Figure 3. Load Dump Waveform Definition



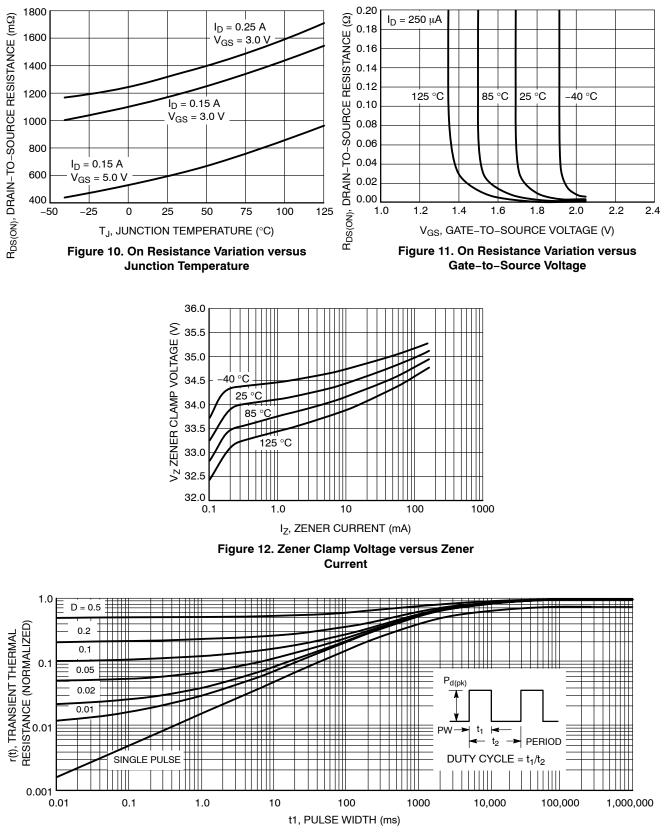


Figure 13. Transient Thermal Response for NUD3124LT1G

APPLICATIONS INFORMATION

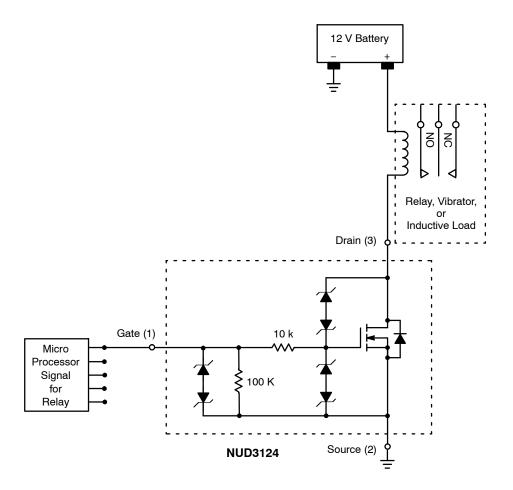


Figure 14. Applications Diagram



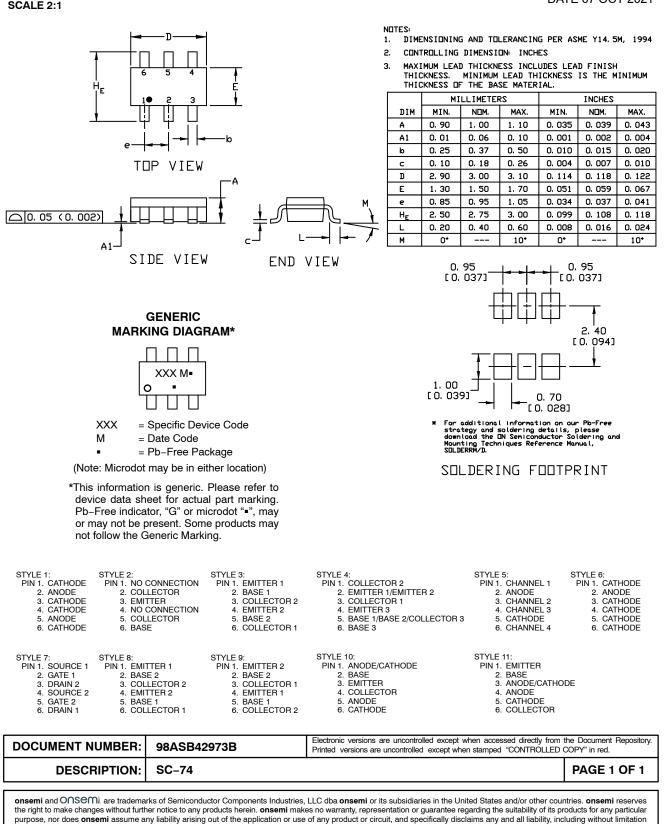


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